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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/809,418	03/26/2004	Masahiko Hasunuma	04173.0447 7844	
7590 08/04/2005			EXAMINER	
Finnegan, Henderson, Farabow, Garrett & Dunner, L.L.P. 1300 I Street, N.W. Washington, DC 20005-3315			PHAM, LONG	
			ART UNIT	PAPER NUMBER
			2814	
			DATE MAILED: 08/04/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)					
Office Action Summany	10/809,418	HASUNUMA ET AL.					
Office Action Summary	Examiner	Art Unit					
•	Long Pham	2814					
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).							
Status							
1) Responsive to communication(s) filed on	1) Responsive to communication(s) filed on						
2a) This action is FINAL . 2b) ⊠ This	action is non-final.	·					
3) Since this application is in condition for allowan							
closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 45	3 O.G. 213.					
Disposition of Claims							
4) Claim(s) <u>1-20</u> is/are pending in the application.	4) Claim(s) 1-20 is/are pending in the application.						
4a) Of the above claim(s) is/are withdraw	4a) Of the above claim(s) is/are withdrawn from consideration.						
5)⊠ Claim(s) <u>4-8,15 and 16</u> is/are allowed.							
6)⊠ Claim(s) <u>1-3,9-14 and 17-20</u> is/are rejected.	6)⊠ Claim(s) <u>1-3,9-14 and 17-20</u> is/are rejected.						
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/or	election requirement.						
Application Papers							
9)☐ The specification is objected to by the Examiner							
10)⊠ The drawing(s) filed on <u>10 August 2004</u> is/are: a)⊠ accepted or b)⊡ objected to by the Examiner.							
Applicant may not request that any objection to the o	lrawing(s) be held in abeyance. See	37 CFR 1.85(a).					
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11) The oath or declaration is objected to by the Exa	aminer. Note the attached Office	Action or form PTO-152.					
Priority under 35 U.S.C. § 119							
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 							
Attachment(s)							
Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948)	4) Interview Summary (Paper No(s)/Mail Da	(PTO-413) te					
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 06/30/05,03/26/04.		atent Application (PTO-152)					

Application/Control Number: 10/809,418 Page 2

Art Unit: 2814

DETAILED ACTION

Election/Restrictions

1. Applicant's election without traverse of claims 1-20 in the reply filed on 06/16/05 is acknowledged.

Claim Rejections - 35 USC § 112

- 2. The following is a quotation of the second paragraph of 35 U.S.C. 112:

 The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.
- 3. Claim 1 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

In claim 1, line 10, it is unclear what side of the substrate is "center side".

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 1, 2, 3, 9, 10, 11, 12, 13, 14, 17, 18, 19, and 20, to the extent as understood and taught by the original specification, are rejected under 35 U.S.C. 103(a) as being unpatentable over Takahisa (Japan 06-188240).

With respect to claims 1 and 13, Takahisa teaches a semiconductor device (see figs. 1-7 and English abstract):

Application/Control Number: 10/809,418

Art Unit: 2814

a semiconductor substrate 10;

at least one layer (18a,18b,18c) of a first insulating film formed above the semiconductor substrate, an entire layer of the first insulating film being separated at least near four corners of the semiconductor substrate by a lacking portion 18Q that extends along the four corners;

a second insulating film 22 covering a side face of the entire layer of the first insulating film in the lacking portion on a center side of the semiconductor substrate or is formed in the lacking portion and the first insulating film and having a relative dielectric constant of over 3.8 (since the second insulating film is made of SiN, its dielectric constant is inherently greater than 3.8). Further with respect to claim 1, since the first insulating layer is made of SOG, it inherently has a low dielectric constant, including values that is less than 3.8.

With respect to claims 2 and 14, Takahisa further teaches the lacking portion 18Q is in the first insulating film is formed near an entire peripheral edge of the semiconductor substrate. See fig. 2.

With respect to claim 3, Takahisa further teaches the second insulating film covers a side face of the entire layer of the first insulating film in the lacking portion also on a peripheral edge side of the semiconductor substrate. See fig. 3.

With respect to claims 9 and 17, Takahisa further teaches the first insulating film is constituted of a plurality of layers 18a,18b,18c.

With respect to claims 10 and 18, 11 and 19, and 12 and 20, Takahisa does not teach that the range for width of lacking portion, the range for the width of the insulating film, and the range for the width for a side of the lacking portion as recited.

However, it would have been obvious to one of <u>ordinary skill</u> in the art of making semiconductor devices to determine the workable or optimal values or

Art Unit: 2814

ranges for these ranges through routine experimentation and optimization to obtain optimal or desired device performance because these are result-effective variables and there is no evidence indicating they are critical or produce any unexpected results and it has been held that it is not inventive to discover the optimum or workable ranges of a result-effective variable within given prior art conditions by routine experimentation. See MPEP 2144.05.

Allowable Subject Matter

6. Claims 4-8 and 15-16 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Long Pham whose telephone number is 571-272-1714. The examiner can normally be reached on M-F, 7:30AM-3:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael Fahmy can be reached on 571-272-1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Application/Control Number: 10/809,418

Art Unit: 2814

Page 5

Long Pham

Primary Examiner

Primary Examiner
Art Unit 2814

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